NSN 5961-01-243-4329

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-243-4329 **Inclosure Material:** Metal **Overall Length:** 2.225 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 1.063 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage and 300.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 30.00 milliamperes forward current, average nanoamperes and 150.00 amperes collector current, dc and 3000.00 amperes collector current, dc preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No